

Enhancement of photocatalytic property on ZnS/MoS₂ composite under visible light irradiation

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Abstract: In this paper, the composite ZnS/MoS₂ was obtained via two steps including solvothermal methods. The as-synthesized sample was characterized by X-ray diffraction (XRD), scanning electron microscopy (SEM) and UV-Vis. diffuse reflectance spectra (DRS). The photocatalytic activity of the product was evaluated through photocatalytic degradation of Rhodamine B (Rh B) under UV-Vis. light irradiation; the electrical conductivity of ZnS/MoS₂ composites was significantly improved compared to ZnS, MoS₂, respectively. The results showed that the ZnS/MoS₂ composite photocatalyst possesses better photocatalytic activity in degrading Rh B than the single ZnS or the single MoS₂. The better photocatalytic properties may be due to the synergetic effect of two semiconductors, because of which electrons and holes were separated effectively. And its specific microstructure played an active role in evaluating photocatalytic performance.

1 Introduction

Environmental degradation is one of the challenging phenomena due to the increasing rate of the industrialization in the world wide. Especially, organic dyes have been widely used in the plastic, paper, textile, and other chemical industries in our lives [1-3]. And it can cause environmental pollution.

However, photocatalysis is one of the promising methods to remove the organic components from waste water. Semiconductor photocatalysts have attracted a subject of extensive interest due to their fundamental importance applications for solving energy and pollution problems. Recently, molybdenum disulfide (MoS₂), shows great potential for visible light irradiated photocatalysis applications. More and more researchers have been extensively investigated MoS₂ as a promising candidate for many materials, due to its excellent electrical carrier mobility, high chemical reactivity and optical properties [4-7]. For instance, Xiuquan Gu [8] et al. obtained MoS₂/Ag₃PO₄ hybrids by incorporating MoS₂ nanosheets during the preparation process of Ag₃PO₄ microparticles. The paper pointed out that the photocatalytic activity of MoS₂/Ag₃PO₄ hybrid got improved owing to compositing with trace amounts MoS₂. The group of Aiyong Zhang [9] prepared layer-controlled MoS₂ on three-dimensional Bi₂S₃ micro-flower through sacrificial templating strategy. The paper showed that 3D flower-like hybrid nanostructures make MoS₂/ Bi₂S₃ to display great photocatalysis under visible light irradiation.

Similarly, among the plenty of metal sulfide photocatalysts, especially, ZnS, have been paid more

attention from the scientific research owing to their optical properties and unique catalytic functions. However, ZnS is responsive only in ultraviolet light region. To address this issue, many means have been used, such as nanomaterials morphology modification and semiconductor compositing. These methods are proved to be effective, and the best way is meeting the energy demands of ZnS with wide band-gap to maintain the catalytic activity [10-11]. Longxin Hu [12] et al. reported that SnO₂/ZnS nanocomposite was prepared by one step hydrothermal method. It was found that the compound showed the great photocatalytic activity. The photocatalytic degradation of RhB (Rhoadmine B) reached 95% at given time. In Baibiao Huang's group [13], they prepared ZnS microspheres with Mn-doping by a facile solvothermal route. And it was found that Mn-doping ZnS exhibited better photocatalytic performance than pure ZnS.

Owing to there have been few studies related to ZnS/MoS₂ composite. In this paper, we successfully prepared semiconductor of MoS₂ decorated with ZnS as catalyst for efficient degradation of dye. Therefore, we pay attention to the ZnS nanoparticles coated MoS₂ nanosheets system connecting two chemically stable and inexpensive multifunctional semiconductor materials together. In this system, MoS₂ nanosheets work as narrow band gap p-type semiconductor and ZnS serves as wide band-gap n-type semiconductor. The experimental reagents are simple and easy to get and the reaction conditions are simple and controllable. Experiment results indicate that ZnS composite MoS₂ exhibit superior photocatalyst performance towards RhB.

2 Experimental

In a typical procedure, 1.5 mmol Na_2MoO_4 and 15 mmol $\text{C}_3\text{H}_7\text{NO}_2\text{S}$ were dissolved in 80 ml deionized water. Then, the solution was transferred into a Teflon-lined stainless-steel autoclave, which was sealed and heated at 220°C for 24 h, and then cool down to room temperature. The as-prepared precipitates were washed by ethyl alcohol and distilled water three times respectively. Then the black powder was collected and dried in vacuum at 80°C for 12 h. The black precipitate was denoted as MoS_2 . 0.1g thioacetamide (CH_3CSNH_2), 0.6758g zinc acetate ($\text{Zn}(\text{CH}_3\text{COO})_2$) and 0.245g Sodium Sulfide (Na_2S) were dissolved in 20 ml deionized water. The mixture was full stirred for 2 h at room temperature. Then, the solution was transferred into a Teflon-lined stainless-steel autoclave, which was sealed and heated at 170°C for 24 h, and then cool down to room temperature. Then, the precipitates were collected and washed by ethyl alcohol and distilled water three times respectively. Then obtained powder was dried in vacuum at 60°C for 12 h. The final powder was called ZnS.

0.1 as-prepared MoS_2 , and 0.2g Sodium dodecyl sulfate (SDS), 1.3516g zinc acetate, 0.49g Sodium Sulfide were dissolved in 60 ml deionized water. Then, the solution was transferred into a Teflon-lined stainless-steel autoclave, which was sealed and heated at 170°C for 2 h, and then cool down to room temperature. Then, the precipitates were collected and washed by ethyl alcohol and distilled water three times respectively. Then obtained powder was dried in vacuum at 60°C for 12 h which denoted as ZnS/MoS_2 .

The as-prepared products were characterized by powder X-ray diffraction (XRD) in Bruker D8 diffractometer using $\text{Cu K}\alpha$ radiation. The surface morphology of the samples were observed by a HITACHI S3500 scanning electron microscopy (SEM). The light absorption properties were measured using UV-Vis. diffuse reflectance spectrophotometer U-4100 (DRS) with a wavelength range of 300~800 nm.

The photocatalytic activity of the samples was determined by degradation of Rhodamine B (RhB) in an aqueous solution under visible light irradiation. The photo degradation experiments were carried out under UV-Vis. light irradiation whose source was a 300W Xe lamp. The distance between the xenon lamp and the sample was about 50 cm. In the each experiment, 20 mg photocatalyst was added into 20 mL RhB solution ($C_0=10$ mg/L). Prior to irradiation, the suspension was sonicated for a few minutes and then magnetically stirred in dark for hours to obtain desorption-adsorption equilibrium. At given time intervals, 5 mL of the sample solution was collected and separated through centrifugation. The HITACHI U-4100 UV-Vis. spectrometer was used to determine the concentration of RhB solution during the photocatalytic degradation process.

The electrochemical properties of all the samples were studied using electrochemical workstation (PGZ402, VoltaLab, France) with a three-electrode configuration. The samples were then used to modify screen-printed carbon electrodes (SPCEs) to immobilize antibodies and

enhance the electrochemical signals. $1 \mu\text{l}$ of 1mg/ml ZnS, MoS_2 and ZnS/MoS_2 were spread on the working area of SPECs using a micropipette and the film was dried at room temperature, respectively. All the cyclic voltammetry (CV) measurements were recorded in 0.1M phosphate buffer (PBS, pH7.4) containing 5mM $\text{K}_3[\text{Fe}(\text{CN})_6]$ and $\text{K}_4[\text{Fe}(\text{CN})_6]$ in the potential range of -1000 to +1000mV. A reproducible voltammogram was obtained under steady-state conditions after about five cycles. All the electrochemical impedance spectroscopy (EIS) measurements were carried out in 0.01M PBS containing 5mM $\text{K}_3[\text{Fe}(\text{CN})_6]$ and $\text{K}_4[\text{Fe}(\text{CN})_6]$ in a frequency range from 0.1 to 104 Hz at 220mV.

3 Results and discussion

The XRD patterns of the samples are presented in Figure. 1. There are no other phases and peaks of impurities, demonstrating that all the samples are pure. MoS_2 and ZnS possess the phases corresponding to JCPDS No. 37-1492 ($a = 3.161 \text{ \AA}$ and $b = 3.161 \text{ \AA}$, $c = 12.299 \text{ \AA}$) and 65-5476 ($a=5.404\text{ \AA}$, $b=5.404 \text{ \AA}$, and $c=5.404 \text{ \AA}$) respectively. The XRD pattern of the ZnS/MoS_2 nanohybrid shows MoS_2 major peaks at corresponding to (100), (103), (110) and there are peaks, like (111), (220), (311) observed related to ZnS. And, no other phase is detected in the ZnS/MoS_2 composite before and after the photocatalytic degradation, suggesting that the composite is stable and there is no chemical reaction between MoS_2 and ZnS.

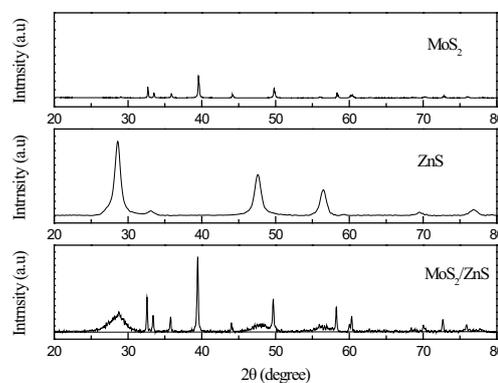


Figure 1. XRD pattern of the samples MoS_2 , ZnS, ZnS/MoS_2 .

The morphologies of the pure MoS_2 , ZnS and ZnS/MoS_2 composite are observed by SEM. Figure.2a exhibits a representative SEM image of pure MoS_2 . The highly monodispersed rough ball-like spheres are obtained which is composed of thin plates as shown in Figure.2b. The nanoplates align radially and tightly to assemble into the uniform spheres. The surfaces of nanoplates are smooth. The SEM micrograph of ZnS in Figure.2c show a large number of plates arranged irregularly together. It can be seen the shapes of plate is the block shaped and the length is about $1 \mu\text{m}$ on average. Regarding to ZnS/MoS_2 composite, it could be seen that the microspheres are organized by hundreds of thin nanoplates and some ZnS plates are together with

sphere with a diameter of 1 μ m (Figure.2d).

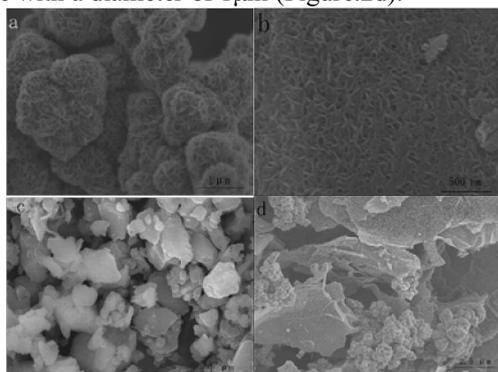


Figure 2. The SEM images of samples (a,b) MoS₂, (c) ZnS, (d) ZnS/MoS₂.

The absorption property is one of the most important properties to characterize the optical property of semiconductor. Figure.3 shows the UV-Vis. diffuse reflectance spectra of ZnS and ZnS/MoS₂ composite. It could be seen that the pure ZnS has an absorption edge occurred at about 375 nm. The absorption edge of the pure ZnS/MoS₂ is approximately at 390 nm. From the picture inset Figure.3, it can be seen UV-Vis. diffuse reflectance spectra of MoS₂. The absorption of ZnS/MoS₂ composite during visible light range is much improved may be owing to MoS₂ which plays an important role.

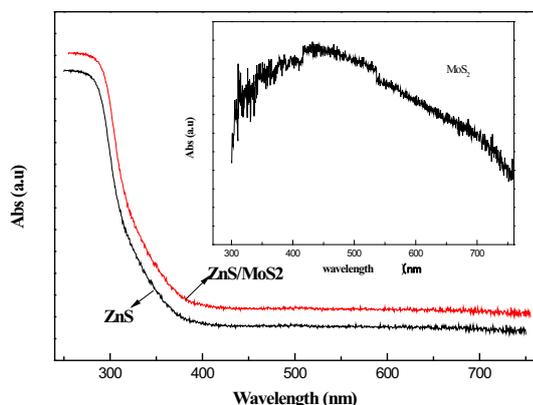


Figure 3. UV-Vis. DRS spectra of the samples ZnS, ZnS/MoS₂, the inset of Figure is UV-Vis. DRS of sample MoS₂.

The photocatalytic activities of as-prepared samples were evaluated by degrading Rhodamine B (Rh B) under UV-Vis. light irradiation. The photodegradation of the RhB as a function of the irradiation time over ZnS/MoS₂ composite is presented in Figure 4. We can see there is no significant change in the concentration curve with time when the photocatalysis is absent, which means Rh B is very stable without photocatalysis only under UV-Vis. light. From the curves of the concentration changes of RhB dye, it can be seen that the photocatalytic degradation rate of all as-prepared samples are increased with the increasing of the reaction time. In 80 minutes, nearly 70% RhB is degraded by ZnS/MoS₂. whereas in 80 minutes, the MoS₂ and ZnS degraded the RhB concentration by 64%, and 82%, respectively. It could be seen that the ZnS/MoS₂ composite exhibits the

best photocatalytic activity among the samples.

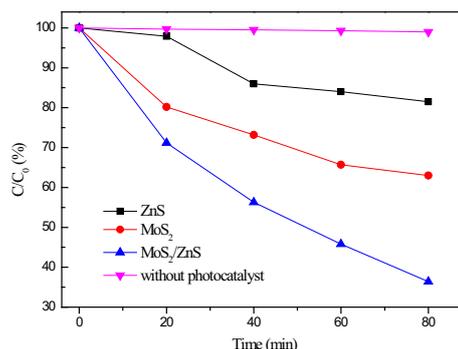


Figure 4. Photocatalytic degradation efficiency of the Rh.B over no photocatalyst, MoS₂, ZnS, ZnS/MoS₂.

In order to further confirm the enhanced conductivity of ZnS/MoS₂, CV curves of ZnS/MoS₂, ZnS, MoS₂ were measured in 0.1M phosphate buffer (pH 7.2) containing 5mM K₃[Fe(CN)₆] and K₄[Fe(CN)₆] as electrolyte. In Figure.5 a pair of symmetric and well-separated redox peaks was observed, indicating that the measured electroconductivity was based on the redox mechanism [14-17]. It was also noted that ZnS/MoS₂ had another cathodic peak at -700 mV may due to the redox of MoS₂. ZnS/MoS₂ exhibited higher current density than single ZnS and MoS₂ due to the accelerated electron transfer by MoS₂. This observation indicates an irreversible electrochemical reduction of MoS₂ when CV is conducted in the inorganic electrolyte at the potential range from 1000 to -1000 mV. It means that the MoS₂ was successfully reduced.

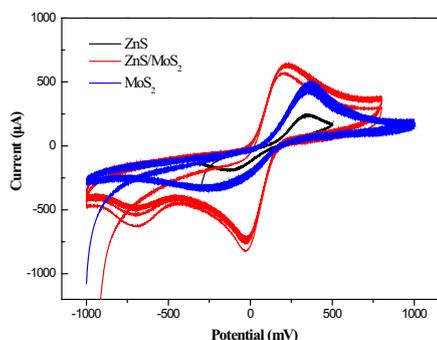


Figure 5. CV curves of MoS₂, ZnS, ZnS/MoS₂ at the scan rate of 100 mV s⁻¹ in 0.1 M PBS (pH 7.4) at RT.

It is obvious that ZnS/MoS₂ composite nanostructures possess more powerful photocatalytic capacity for the degradation of Rh B. As a consequence, a possible mechanism is proposed. According to some papers [18-21], we deduce that MoS₂ and ZnS have matching band potential.

Under irradiation, the photocatalyst could generate electrons and holes. The conduction band and valence band edge positions of MoS₂ are associated with those of ZnS, so both electrons and holes are transferred to MoS₂. Holes transfer to MoS₂ nanoflakes, which increases charge separation. Thus, MoS₂ acts as an oxidation site. In another words, the band potentials of both MoS₂ and ZnS

semiconductors are conducive to prevent the recombination of electrons and holes in the ZnS/MoS₂ composite. In general, the ZnS/MoS₂ composite with special nanostructure and interface increases the visible light absorption and restrains the recombination of electron-hole pairs.

4 Conclusion

In summary, ZnS/MoS₂ composite photocatalyst was got by two steps which in order were solvothermal methods. The microsphere of the composite was composed of hundreds of MoS₂ thin nanoplates and some ZnS plates were together with the sphere about a diameter of 1 μm from the view of morphology. From the photodegradation of the Rh B organic dye we found that the ZnS/MoS₂ composited photocatalyst displayed better photocatalytic activity than both single MoS₂ and single ZnS. As a proof of concept, the ZnS/MoS₂ with good conductivity, superior electron transfer rate and high electrochemical activity is successfully used to detect photocatalytic property.

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